# Thyristors logic level

#### **BT148 series**

MAX.

600R

600

2.5

4

35

g

UNIT

V

A

A

А

k

MAX.

400R

400

2.5

4

35

SYMBOL

а

BT148-

MAX.

500R

500

2.5

4

35

#### **GENERAL DESCRIPTION**

Glass passivated, sensitive gate thyristors in a plastic envelope, intended for use in general purpose switching and phase control applications. These devices are intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

#### PINNING - SOT82

# PINDESCRIPTION1cathode2anode3gatetabanode

#### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT	
V <sub>drm</sub> , V <sub>rrm</sub>	Repetitive peak off-state voltages		-	<b>-400R</b> 400 <sup>1</sup>	<b>-500R</b> 500 <sup>1</sup>	<b>-600R</b> 600 <sup>1</sup>	V
I <sub>T(AV)</sub> I <sub>T(RMS)</sub> I <sub>TSM</sub>	Average on-state current RMS on-state current Non-repetitive peak on-state current	half sine wave; T <sub>mb</sub> ≤ 113 °C all conduction angles half sine wave; T <sub>j</sub> = 25 °C prior to surge	-		2.5 4		A A
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t = 10 ms t = 8.3 ms t = 10 ms	-		35 38 6.1		A A A²s
dl <sub>⊤</sub> /dt	Repetitive rate of rise of on-state current after triggering	$I_{TM} = 10 \text{ A}; I_G = 50 \text{ mA};$ $dI_G/dt = 50 \text{ mA/}\mu\text{s}$	-		50		A/µs
I <sub>GM</sub> V <sub>GM</sub> V <sub>RGM</sub> P <sub>GM</sub>	Peak gate current Peak gate voltage Peak reverse gate voltage Peak gate power		- - -		2 5 5 5		A V V W
P <sub>G(AV)</sub> T <sub>stg</sub> T <sub>j</sub>	Average gate power Storage temperature Operating junction temperature	over any 20 ms period	-40 -		0.5 150 125 <sup>2</sup>		Ç Ç

QUICK REFERENCE DATA

voltages

current

**PIN CONFIGURATION** 

PARAMETER

Repetitive peak off-state

Average on-state current

Non-repetitive peak on-state

RMS on-state current

SYMBOL

V<sub>drm</sub>, V<sub>rrm</sub>

I<sub>T(AV)</sub>

I<sub>TSM</sub>

I<sub>T(RMS)</sub>

**<sup>1</sup>** Although not recommended, off-state voltages up to 800V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15 A/ $\mu$ s.

**<sup>2</sup>** Note: Operation above 110°C may require the use of a gate to cathode resistor of  $1k\Omega$  or less.

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## THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{thj-mb}$	Thermal resistance		-	-	2.5	K/W
R <sub>th j-a</sub>	junction to mounting base Thermal resistance junction to ambient	in free air	-	95	-	K/W

## STATIC CHARACTERISTICS

 $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>GT</sub>	Gate trigger current	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$	-	15	200	μA
	Latching current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$	-	0.17	10	mΑ
	Holding current	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm GT} = 0.1 \text{ A}$	-	0.10	6	mA
V <sub>τ</sub>	On-state voltage	$I_{T} = 5 A$	-	1.23	1.8	V
V <sub>GT</sub>	Gate trigger voltage	$\dot{V}_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$	-	0.4	1.5	V
<u> </u>		$V_{D} = V_{DRM(max)}$ ; $I_{T} = 0.1 \text{ A}$ ; $T_{j} = 110 \text{ °C}$	0.1	0.2	-	V
I <sub>D</sub> , I <sub>R</sub>	Off-state leakage current	$V_D = V_{DRM(max)}^{ORM(max)}; V_R = V_{RRM(max)}; T_j = 125 °C$	-	0.1	0.5	mA

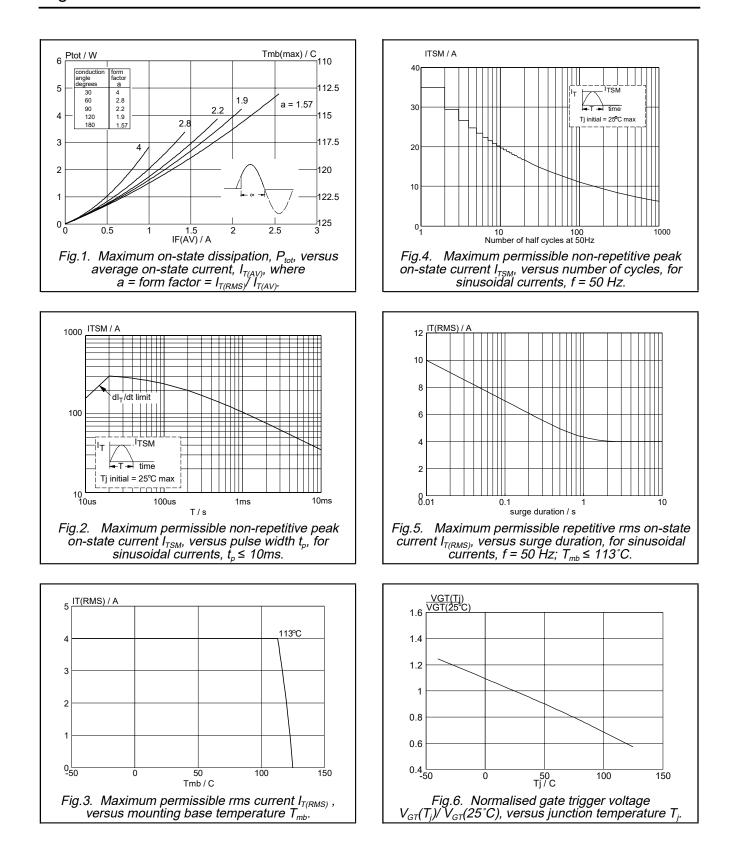
#### **DYNAMIC CHARACTERISTICS**

 $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV <sub>D</sub> /dt	Critical rate of rise of off-state voltage	$V_{DM}$ = 67% $V_{DRM(max)}$ ; T <sub>j</sub> = 125 °C; exponential waveform; R <sub>GK</sub> = 100 Ω	-	50	-	V/µs
t <sub>gt</sub>	Gate controlled turn-on time	$I_{TM} = 10 \text{ A}; V_D = V_{DRM(max)}; I_G = 5 \text{ mA};$ $dI_D/dt = 0.2 \text{ A/us}$	-	2	-	μs
t <sub>q</sub>	Circuit commutated turn-off time		-	100	-	μs

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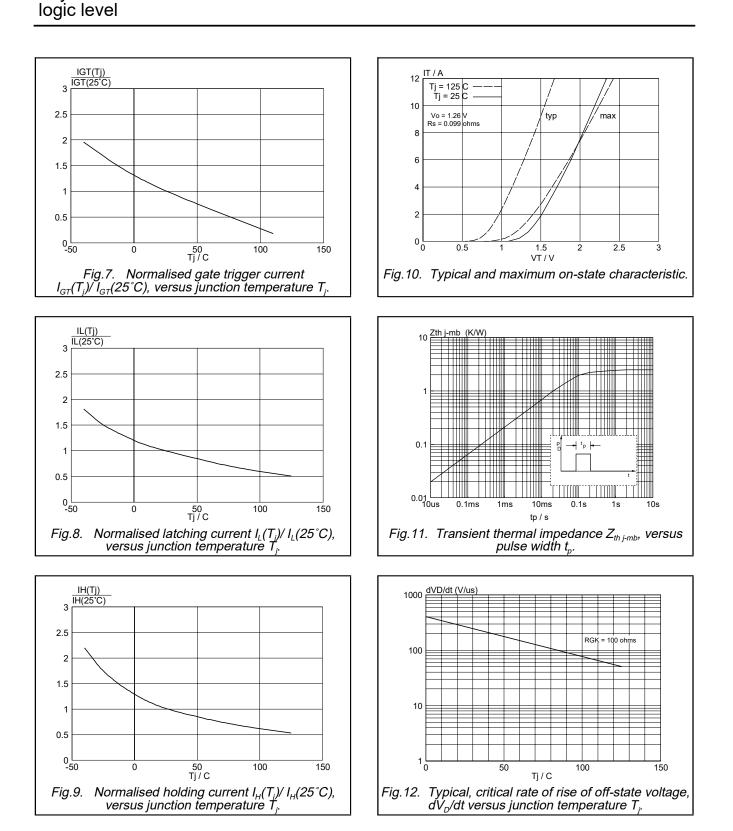


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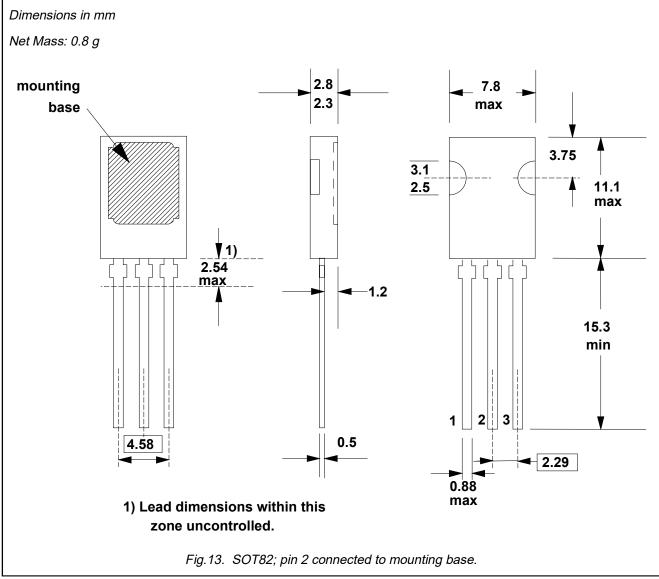


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#### **MECHANICAL DATA**



#### Notes

Refer to mounting instructions for SOT82 envelopes.
Epoxy meets UL94 V0 at 1/8".

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Product specification

#### BT148 series

#### DEFINITIONS

Data sheet status					
Dbjective specification This data sheet contains target or goal specifications for product development.					
Preliminary specification This data sheet contains preliminary data; supplementary data may be published later					
Product specification	Product specification This data sheet contains final product specifications.				
Limiting values					
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability. <b>Application information</b>					
Where application information is given, it is advisory and does not form part of the specification.					
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